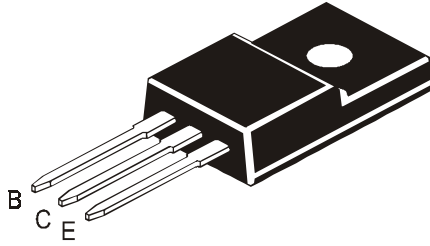


SILICON PLANAR POWER TRANSISTORS

CJF2955 PNP
CJF3055 NPN



**TO-220FP Fully Isolated
Plastic Package**

General Purpose Amplifier and Switching Applications.

ABSOLUTE MAXIMUM RATINGS.

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter (Sustaining) Voltage	$V_{CEO(sus)}$	90	V
Collector Emitter Voltage	V_{CES}	90	V
Emitter Base Voltage	V_{EBO}	5	V
RMS Isolation Voltage (for 1sec,R.H. <30%, $T_A=25^{\circ}C$)	(1) V_{ISOL} (a)	3500	V_{RMS}
	(b)	1500	V_{RMS}
Collector Current	I_C	10	A
Base Current	I_B	6	A
Total Power Dissipation @ $T_c=25^{\circ}C$	$P_{D^{**}}$	30	W
Derate Above $25^{\circ}C$		0.25	W/ $^{\circ}C$
Total Power Dissipation @ $T_a=25^{\circ}C$	P_D	2	W
Derate Above $25^{\circ}C$		0.016	W/ $^{\circ}C$
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 55 to +150	$^{\circ}C$
THERMAL RESISTANCE			
From Junction to Ambient	$R_{th(j-a)}$	62.5	$^{\circ}C/W$
From Junction to Case	$R_{th(j-c)**}$	4	$^{\circ}C/W$
Lead Temperature for Soldering Purpose	T_L	260	$^{\circ}C$

****Measurement made with thermocouple contacting the bottom insulated mounting surface (in a location beneath the die), the device mounted on a heatsink with thermal grease and a mounting torque of ≥ 6 in.lbs.**

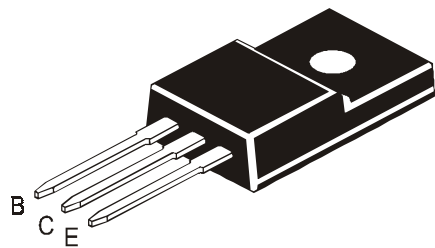
(1) RMS Isolation Voltage : (a) 3500 V_{RMS} with Package in Clip Mounting Position (b) 1500 V_{RMS} with Package in Screw Mounting Position (for 1sec, R.H.<30% , $T_a=25^{\circ}C$; Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$)

ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}C$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter sustaining Voltage	$V_{CEO(sus)}^*$	$I_C=200mA, I_B=0$	90		V
Collector Cut off Current	I_{CBO}	$V_{CB}=90V, I_E=0$		1	μA
	I_{CES}	$V_{CE}=90V, V_{BE}=0$		1	μA
Emitter Cut off Current	I_{EBO}	$V_{EB}=5V, I_C=0$		1	μA

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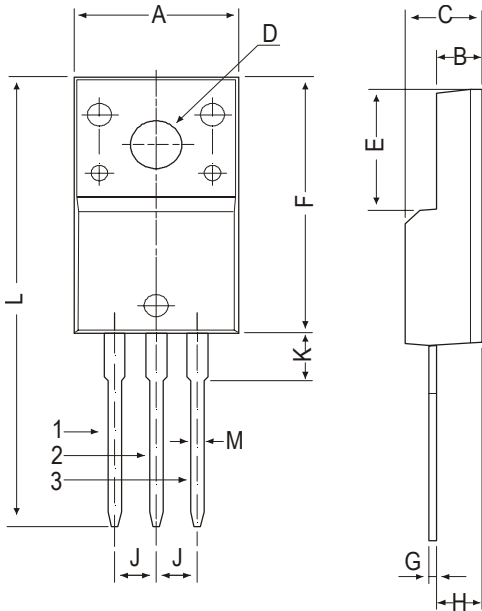
ELECTRICAL CHARACTERISTICS (T_c=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
DC Current Gain	h_{FE}^*	$I_C=4.0A, V_{CE}=4V$ $I_C=10A, V_{CE}=4V$	20 5	100	
Collector Emitter Saturation Voltage	$V_{CE(Sat)}^*$	$I_C=4A, I_B=0.4A$ $I_C=10A, I_B=3.3A$		1 2.5	V V
Base Emitter on Voltage	$V_{BE(on)}^*$	$I_C=4.0A, V_{CE}=4V$		1.5	V
<u>DYNAMIC CHARACTERISTICS</u>					
Current Gain - Bandwidth Product	f_T	$I_C=500mA, V_{CE}=10V$ $f=500kHz$	2		MHz

* Pulse Test: Pulse Width =5ms, Duty Cycle ≤10 %

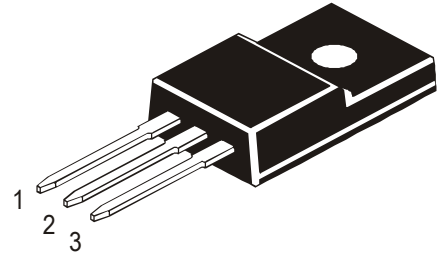
TO-220FP Fully Isolated
Plastic Package

TO-220FP Fully Isolated Plastic Package



DIM	MIN	MAX
A	9.96	10.36
B	2.60	3.00
C	4.50	4.90
D	3.10	3.30
E	7.90	8.20
F	16.87	17.27
G	0.45	0.50
H	2.56	2.96
J	2.34	2.74
K	—	3.08
L	—	30.05
M	—	0.80

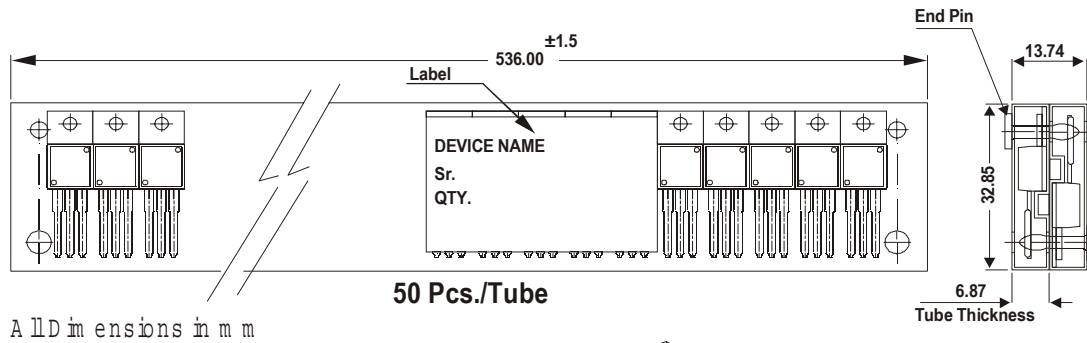
All dimensions in mm.



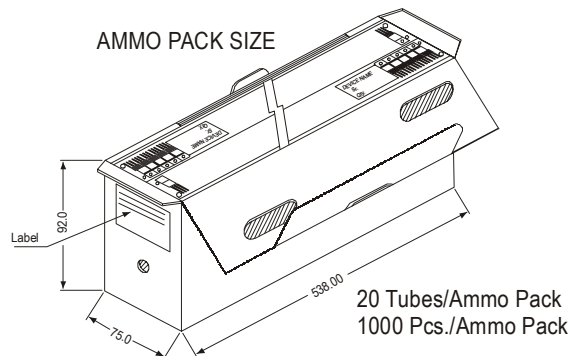
Pin Configuration

1. Base
2. Collector
3. Emitter

TO-220 FP Tube Packing



AMMO PACK SIZE



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220FP	200 pcs/polybag 50 pcs/tube	396 gm/200 pcs 135 gm/50 pcs	3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"	1K 1K	17" x 15" x 13.5" 19" x 19" x 19"	16K 10K	36 kgs 28 kgs

**TO-220FP Fully Isolated
Plastic Package****Disclaimer**

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